Diode Semiconductor Device - Page 1 of 1



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| Glass | |
|-----------|--|
| Overall L | ength: |
| 0.250 inc | - |
| Terminal | Length: |
| 1.500 inc | hes |
| Overall [| Diameter: |
| 0.076 inc | hes |
| Mounting | g Method: |
| Terminal | |
| Features | Provided: |
| Hermetic | ally sealed case |
| Semicon | ductor Material: |
| Silicon | |
| Current | Rating Per Characteristic: |
| 1.00 amp | eres repetitive peak forward current |
| Maximur | n Operating Tempurature Per Measurement Point: |
| 160.0 de | grees celsius ambient air |
| Termina | Type And Quantity: |
| 2 uninsul | ated wire lead |
| Shelf Lif | 9: |
| N/a | |
| Unit Of M | leasure: |
| | |
| Demilita | ization: |
| No | |
| Fiig: | |
| A110a0 | |